Dual USB Power Control Switch with<br>Over-Current/Voltage Protection<br>PA3526

## Features

2 independent switches
Individual open-drain fault flag pins
2.7 V to 5.5 V input

500 mA continuous load current per port
$140 \mathrm{~m} \Omega$ maximum on-resistance
$1 \mu \mathrm{~A}$ Maximum Standby Supply Current
Thermal shutdown
Undervoltage lockout (UVLO)
o Active-high or active-low enable versions

## Applications

- USB Power Management
- Hot plug-in power supplies
o Battery - Charger circuits


## Ordering Information

| Part Number | Enable | Temperature Range |
| :--- | :---: | :---: |
| PA3526-H | Active High | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| PA3526-L | Active Low | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |

## Pin configuration PA3526X



## Pin Description

| Pin <br> Number | Pin Name |  |
| :---: | :---: | :--- |
| 1,4 | EN(A/B) | Enable (Input): Logic-compatible enable input. High input > 2.1V typical. <br> Low input <1.9V typical (H active high, L active low). |
| 2,3 | FLG(A/B) | Fault Flag (Output): Active-low, open-drain output. Indicates overcurrent, and thermal shutdown, UVLO, <br> OVLO. |
| 6 | GND | Ground. |
| 7 | IN | Supply Input: Output MOSFET drain. Also supplies IC's internal circuitry. |
| 8,5 | OUT(A/B) | Switch Output: Output MOSFET source. Typically connect to switched side of load. |

## Detailed description <br> \section*{Power switch}

The power switch is an $N$-channel MOSFET with a maximum on-state resistance of $500 \mathrm{~m} \Omega\left(\mathrm{~V}_{\mathbb{I N}}=5 \mathrm{~V}\right)$. The power switch supplies a minimum of 100 mA per switch.
Enable (EN or EN)
The logic enable disables the power switch and the bias for the charge pump, driver, and other circuitry to reduce the supply current to less than $1 \mu \mathrm{~A}$ when a logic high is present on EN (PA3526-L) or a logic low is present on EN (PA3526-H). The enable input is compatible with both TTL and CMOS logic levels.

## Driver

The driver controls the gate voltage of the power switch. To limit large current surges the driver incorporates circuitry that controls the rise times and fall times of the output voltage.

## Charge pump

An internal charge pump supplies power to the driver circuit and provides the necessary voltage to pull the gate of the MOSFET above the source.

## Fault Flag FLG (A/B)

FLG is an N-channel, open-drain MOSFET output. The fault-flag is active (low) for one or more of the following conditions: under-voltage, current limit, or thermal shutdown. The flag output MOSFET is capable of sinking a 10 mA load to typically 100 mV above ground.
Multiple FLG pins may be "wire NO Red" to a common pull-up resistor.
Thermal shutdown
An internal thermal-sense circuit shuts off the power switch when the junction temperature rises to approximately $150^{\circ} \mathrm{C}$.
Hysteresis is built into the thermal sense circuit.
Over-voltage lockout
OVLO (over-voltage lockout) prevents the output MOSET from turning on if $\mathrm{V}_{\mathrm{IN}}$ exceeds approximately 6.5 V . Over voltage detection function only when at least one switch is enabled


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## Current sense (CS)

A sense FET monitors the current supplied to the load. When an overload or short circuit is encountered, the current-sense circuitry sends a control signal to the driver. The driver in turn reduces the gate voltage and sends the power FET into its saturation region, which switches the output into a constant current mode.

## Under-voltage lockout

UVLO (under-voltage lockout) prevents the output MOSFET from turning on until $\mathrm{V}_{\mathbb{I}}$ exceeds approximately 2.3 V . In the under-voltage state, the FLAG will be low. After the switch turns on, if the voltage drops below approximately 2.1 V , UVLO shuts off the output MOSFET and signals fault flag. Under-voltage detection functions only when at least one switch is enabled.

## Absolute Maximum Ratings (Note1)

| Parameter | Maximum | Units |
| :--- | :---: | :---: |
| Supply Voltage $\left(\mathrm{V}_{\text {IN }}\right)$ | 6 | V |
| Fault Flag Voltage $\left(\mathrm{V}_{\mathrm{FLG}}\right)$ | 6 |  |
| Fault Flag Current $\left(\mathrm{l}_{\mathrm{FLG}}\right)$ | 50 | mA |
| Output Voltage $\left(\mathrm{V}_{\mathrm{OUT}}\right)$ | 6 | V |
| Output Current $\left(\mathrm{l}_{\mathrm{oUT}}\right)$ | Internally Limited | A |
| Control input $\left(\mathrm{V}_{\mathrm{EN}}\right)$ | -0.3 to 12 | V |
| Storage Temperature $\left(\mathrm{T}_{\mathrm{S}}\right)$ | -65 to 150 | ${ }^{\circ} \mathrm{C}$ |

Operating Ratings (Note 2)

| Parameter | PA3526 |
| :--- | :---: |
| Supply Voltage $\left(\mathrm{V}_{\text {IV }}\right)$ | 2.7 V to 5.5 V |
| Ambient Operating Temperature $\left(\mathrm{T}_{\mathrm{A}}\right)$ | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |

## Electrical Characteristics

TA $=25 \circ \mathrm{C}, \mathrm{VIN}=+5 \mathrm{~V}$; unless noted

| Parameter | Condition | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Supply Current | Note 3, switch off, OUT = open, |  | 0.5 | 1 | $\mu \mathrm{A}$ |
|  | Note 3, all switches on, OUT = open, |  | 120 | 200 |  |
| Enable Input Threshold | Low-to-high transition |  | 2.1 | 2.4 | V |
|  | High-to-low transition, Note 3 | 0.8 | 1.9 |  |  |
| Enable Input Current | $\mathrm{V}_{\mathrm{EN}}=0 \mathrm{~V} \mid 5.5 \mathrm{~V}$ | -0.5 | $\pm 0.01$ | 0.5 | $\mu \mathrm{A}$ |
| Enable Input Capacitance |  |  | 1 |  | pF |
| Switch Resistance | $\mathrm{V}_{\text {IN }}=5 \mathrm{~V}$, $\mathrm{l}_{\text {OUT }}=500 \mathrm{~mA}$, each switch |  | 100 | 140 | m |
|  | $\mathrm{V}_{\text {IN }}=2,7 \mathrm{~V}$, $\mathrm{l}_{\text {OUT }}=500 \mathrm{~mA}$, each switch |  | 140 | 180 |  |
| Output Turn-On Delay | $\mathrm{R}_{\mathrm{L}}=10 \Omega$, each output |  | 0.5 |  | ms |
| Output Turn-On Rise Time | $R_{L}=10 \Omega$, each output |  | 1 |  | ms |
| Output Turn off Delay | $\mathrm{R}_{\mathrm{L}}=10 \Omega$, each output |  | 1 | 20 | $\mu \mathrm{S}$ |
| Output Turn off Fall Time | $\mathrm{R}_{\mathrm{L}}=10 \Omega$, each output |  | 1 | 20 | $\mu \mathrm{S}$ |
| Output Leakage Current | each output (output disabled) |  |  | 10 | $\mu \mathrm{A}$ |
| Continuous Load Current | each output | 0.5 |  |  | A |
| Short-Circuit Current Limit | each output (enable into load) $\mathrm{V}_{\text {OUT }}=4.0 \mathrm{~V}$ | 0.5 | 1.2 | 1.9 | A |
|  | each output (enable into load) $\mathrm{V}_{\text {Out }}=0.1 \mathrm{~V}$ |  | 1 | 1.5 |  |
| Current-Limit Threshold | Ramped load applied to enabled output, $\mathrm{V}_{\text {Out }} \leq 4.0 \mathrm{~V}$ |  | 1.6 | 2.2 | A |
| Over temperature Shutdown Threshold | $\mathrm{T}_{\mathrm{J}}$ increasing |  | 135 |  | ${ }^{\circ} \mathrm{C}$ |
|  | $\mathrm{T}_{\mathrm{J}}$ decreasing |  | 125 |  |  |
| Error Flag Output Resistance | $\mathrm{V}_{\mathrm{IN}=5,0 \mathrm{~V}, \mathrm{I}_{\mathrm{L}}=10 \mathrm{~mA}}$ |  | 10 | 25 | $\Omega$ |
|  | $\mathrm{V}_{\mathrm{IN}^{\prime}}=3,3 \mathrm{~V}, \mathrm{I}_{\mathrm{L}}=10 \mathrm{~mA}$ |  | 11 | 35 |  |
|  | $\mathrm{V}_{\text {IN }}=2,7 \mathrm{~V}, \mathrm{I}_{\mathrm{L}}=10 \mathrm{~mA}$ |  | 12 | 40 |  |
| Error Flag Off Current | $\mathrm{V}_{\mathrm{FLAG}}=5 \mathrm{~V}$ |  | 0.01 | 1 | $\mu \mathrm{A}$ |
| UVLO Threshold | $\mathrm{V}_{\text {IN }}$ increasing |  | 2.3 |  | V |
|  | $\mathrm{V}_{\text {IN }}$ decreasing |  | 2.1 |  |  |
| OVLO Threshold | $\mathrm{V}_{\text {IN }}$ increasing |  | 6.5 |  | V |
|  | $\mathrm{V}_{\text {IN }}$ decreasing |  | 6.3 |  |  |

Note 1: Exceeding the absolute maximum rating may damage the device.
Note 2: The device is not guaranteed to function outside its operating rating
Note 3: Off is $\delta 0.8 \mathrm{~V}$ and on is $\varepsilon 2.4 \mathrm{~V}$ for the PA3526-H. Off is $\varepsilon 2.4 \mathrm{~V}$ and on is $\delta 0.8 \mathrm{~V}$ for the PA3526-L. The enable input has approximately 200 mV of hysteresis.

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## Block Diagram



Pad Location PA3526


Pad Location Coordinates

| $\mathbf{N}$ | Pad Name |  | Pad size <br> $(\propto \mathbf{m} \times \mathbf{m})$ | Coordinates, $\mu \mathrm{m}$ |  |
| :---: | :--- | :---: | :---: | :---: | :---: |
|  |  | X |  |  |  |
| 1 | ENA | $136 \times 120$ | 323.5 | 220 |  |
| 2 | FLGA | $136 \times 120$ | 1111.5 | 237.5 |  |
| 3 | FLGB | $136 \times 120$ | 2187.5 | 237.5 |  |
| 4 | ENB | $136 \times 120$ | 2975.5 | 220 |  |
| 5 | OUTB | $140 \times 130$ | 3079 | 1260.5 |  |
| 5 | OUTB | $140 \times 130$ | 3079 | 1465.5 |  |
| 5 | OUTB | $140 \times 130$ | 3079 | 1664 |  |
| 6 | GND | $140 \times 130$ | 3079 | 1943.5 |  |
| 7 | IN | $140 \times 130$ | 1650 | 1260.5 |  |
| 7 | IN | $140 \times 130$ | 1650 | 1462.5 |  |
| 7 | IN | $140 \times 130$ | 1650 | 1664 |  |
| 8 | OUTA | $140 \times 130$ | 220 | 1259 |  |
| 8 | OUTA | $140 \times 130$ | 220 | 1465.5 |  |
| 8 | OUTA | $140 \times 130$ | 220 | 1664.5 |  |

Chip size $3.3 \times 2.15 \mathrm{~mm}$

